

# High Efficiency NiMH Battery Charger for Photovoltaic Sources

# DESCRIPTION

The TS52002 is a DC/DC synchronous switching MPPT Regulator with fully integrated power switches, internal compensation, and full fault protection. The TS52002 utilizes a temperature-independent photovoltaic Maximum Power Point Tracking (MPPT-Lite<sup>TM</sup>) calculator to optimize power output from the source. The switching frequency of 1MHz enables the use of small filter components, resulting in smaller board space and reduced BOM costs.

# APPLICATIONS

#### 1-cell and 2-cell NiMH chargers

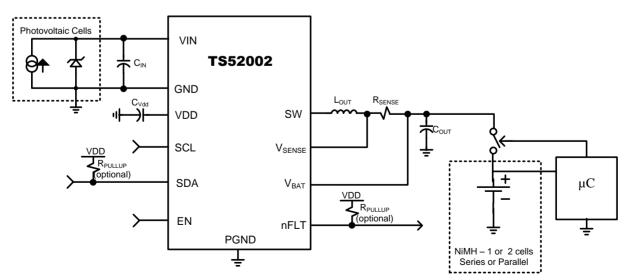
- Portable solar chargers
- Off-grid systems
- Wireless sensor networks
- Smoke detectors
- HVAC controls

## **FEATURES**

- Utilizes a temperature-independent PV MPPT-Lite<sup>TM</sup> regulation scheme
- V<sub>BAT</sub> reverse current blocking
- Up to 1.5A continuous output current
- High efficiency up to 92% at typical load
- Current mode PWM control in constant voltage
- Input supply under-voltage lockout
- Full protection for VBAT over-voltage
- Device over-current and over-temperature protection
- I2C status interface
- VBAT status indication

### SUMMARY SPECIFICATION

- Wide Input Voltage Range: 3.2V to 7.2V
- Packaged in a 16pin QFN (4x4)



# TYPICAL APPLICATION



# PINOUT

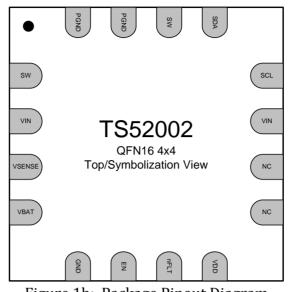


Figure 1b: Package Pinout Diagram

# **PIN DESCRIPTION**

Pin Symbol	Pin #	Function	Description
SW	1	Switching Voltage Node	Connected to 4.7uH (typical) inductor
VIN	2	Photovoltaic Input Voltage	Input voltage
VSENSE	3	Current Sense Positive Input	Positive input for the MPP current loop.
VBAT	4	Output Voltage	Regulator Feedback Input
GND	5	GND	Primary ground for the majority of the device except the low-side power FET.
EN	6	Enable Input	Above 2.2V the device is enabled. GND the pin to disable the device. Includes internal pull-up.
nFLT	7	Inverted Fault	Open-drain output.
VDD	8	Internal 3.3V Supply Output	Connected to 100nF capacitor to GND
	9	Unused	GND in application
	10	Unused	GND in application
VIN	11	Photovoltaic Input Voltage	Input voltage
SCL	12	Clock Input	I <sup>2</sup> C clock input.
SDA	13	Data Input/Output	I <sup>2</sup> C data open-drain output.
SW	14	Switching Voltage Node	Connected to 4.7uH (typical) inductor
PGND	15	Power GND	GND supply for internal low-side FET/integrated diode
PGND	16	Power GND	GND supply for internal low-side FET/integrated diode



# FUNCTIONAL BLOCK DIAGRAM

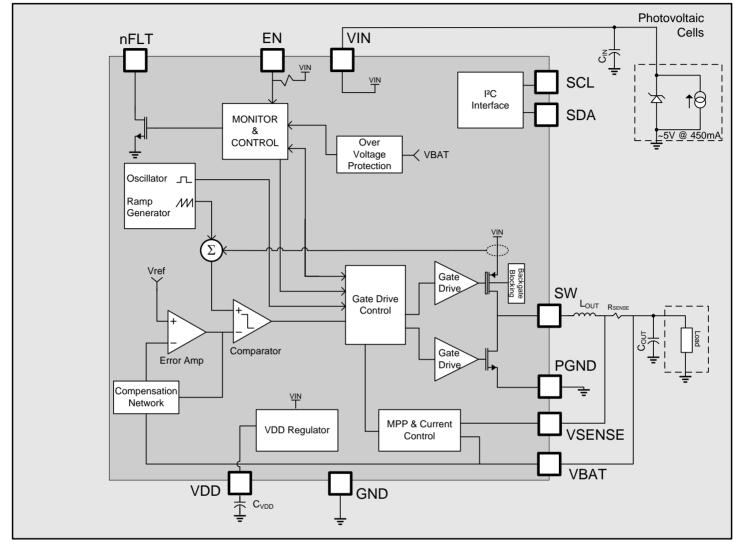


Figure 2: TS52002 Block Diagram



#### **ABSOLUTE MAXIMUM RATINGS**

Over operating free-air temperature range unless otherwise noted<sup>(1,2,3)</sup>

Parameter	Range	Unit
VIN, EN, nFLT, SCL, SDA, VBAT, VSENSE	-0.3 to 8	V
SW	-1 to 8.8	V
VDD	-0.3 to 3.6	V
Operating Junction Temperature Range, T <sub>J</sub>	-40 to 125	°C
Storage Temperature Range, T <sub>STG</sub>	-65 to 150	°C
Electrostatic Discharge – Human Body Model	±2k	V
Electrostatic Discharge – Machine Model	+/-200	V
Lead Temperature (soldering, 10 seconds)	260	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) ESD testing is performed according to the respective JESD22 JEDEC standard.

### THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit					
$\theta_{JA}$	Thermal Resistance Junction to Air (Note 1)	50	°C/W					
Noto 1. Accumos	ato 1. Accument $4/4$ OEN 16 in 1 in 2 area of 2 or conner and $25\%$ ambient temperature							

Note 1: Assumes 4x4 QFN-16 in 1 in<sup>2</sup> area of 2 oz copper and 25°C ambient temperature.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Тур	Max	Unit
VIN	Photovoltaic Input Operating Voltage	3.2	5.3	7.2	V
R <sub>SENSE</sub>	Sense Resistor		50		mΩ
L <sub>OUT</sub>	Output Filter Inductor Typical Value (Note 1)		4.7		uH
Соит	Output Filter Capacitor Typical Value (Note 2)		4.7		uF
C <sub>OUT-ESR</sub>	Output Filter Capacitor ESR			100	mΩ
Cin	Input Supply Bypass Capacitor Typical Value (Note 3)	3.3	10		uF
C <sub>VDD</sub>	VDD Supply Bypass Capacitor Value (Note 2)	70	100	130	nF
T <sub>A</sub>	Operating Free Air Temperature	-40		85	°C
TJ	Operating Junction Temperature	-40		125	°C

Note 1: For best performance, an inductor with a saturation current rating higher than the maximum V<sub>BAT</sub> load requirement plus the inductor current ripple. Note 2: For best performance, a low ESR ceramic capacitor should be used.

Note 3: For best performance, a low ESR ceramic capacitor should be used. If C<sub>IN</sub> is not a low ESR ceramic capacitor, a 0.1uF ceramic capacitor should be added in parallel to C<sub>IN</sub>.



### **CHARACTERISTICS**

Electrical Characteristics,  $T_1 = -40C$  to 125C, VIN = 5.3V (unless otherwise noted)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
VIN Supply	Voltage					
V <sub>IN</sub>	Photovoltaic Voltage Input		3.2	5.3	7.2	V
I <sub>CC-NORM</sub>	Quiescent current Normal Mode	$I_{LOAD} = 0A$		3		mA
I <sub>CC-STBY</sub>	Quiescent current Disable Mode	EN = 0V		10	50	uA
VBAT Leaka	ge					
I <sub>BAT-LEAK</sub>	Leakage Current From Output	EN = 0V			10	uA
I <sub>BAT-BACK</sub>	Reverse Current	VBAT > VIN			10	uA
VIN Under-V	/oltage Lockout					
VIN-uv	Input Supply Under-Voltage Threshold	VIN Increasing		3.15		V
VIN-UV_HYST	Input Supply Under-Voltage Threshold Hysteresis		100	200		mV
OSC						
Fosc	Oscillator Frequency		0.9	1	1.1	MHz
nFLT Open l	Drain Output					
I <sub>OH-nFLT</sub>	High-Level Output Leakage	$V_{nFLT} = 5.3V$		0.1		uA
V <sub>OL-nFLT</sub>	Low-Level Output Voltage	$I_{nFLT} = -1mA$			0.4	V
	A Input Voltage Thresholds					
V <sub>IH</sub>	High Level Input Voltage		2.2			V
V <sub>IL</sub>	Low Level Input Voltage				0.8	V
V <sub>HYST</sub>	Input Hysteresis			200		mV
T	Input Leakage	$V_{EN}=VIN$		0.1		uA
I <sub>IN-EN</sub>	input Leakage	$V_{EN}=0V$		-2.0		uA
т	Input Leakage	V <sub>SCL</sub> =VIN		55		uA
I <sub>IN-SCL</sub>	прис сеакаде	$V_{SCL}=0V$		-0.1		uA
т	Input Leakage	V <sub>SDA</sub> =VIN		0.1		uA
I <sub>IN-SDA</sub>	прит цеакаде	$V_{SDA}=0V$		-0.1		uA
Vol-sda	Low-Level Output Voltage	$I_{SDA} = -1mA$			0.4	V
Thermal Shu	utdown					
TSD	Thermal Shutdown Junction Temperature		150	170		С
TSD <sub>HYST</sub>	TSD Hysteresis			10		С



### **CHARGER CHARACTERISTICS**

Electrical Characteristics, T<sub>J</sub> = -40C to 125C, VIN = 5.3V (unless otherwise noted)

Symbol	Parameter	Condition	Min	Тур	Max	Unit		
Charging Regulator: L=4.7uH and C=4.7uF								
I <sub>BAT-FC</sub>	Output Current Limit	$I_{BAT} = 1.5A$	I <sub>ват</sub> - 10%	I <sub>BAT</sub>	I <sub>BAT</sub> + 10%	А		
V <sub>BAT-TO</sub>	Termination Voltage		4.16	4.2	4.24	V		
D	High Side Switch On Resistance	$I_{SW} = -1A, T_J = 25C$		250		mΩ		
R <sub>DSON</sub>	Low Side Switch On Resistance	$I_{SW} = 1A, T_J = 25C$		150		mΩ		
I <sub>BAT</sub>	Max Output Current			1.5		Α		
I <sub>OCD</sub>	Over-Current Detect	HS switch current		2.5		Α		
V	V <sub>BAT</sub> Over-Voltage Threshold		101%	102%	103%			
V <sub>BAT-OV</sub>	VBAT OVEI-VOItage TIITesiloiu		VBAT	$V_{BAT}$	VBAT			
V	V <sub>BAT</sub> Over-Voltage Hysteresis		0.2%	0.4%	0.6%			
V <sub>BAT-OV_HYST</sub>	VBAT OVEL-VOITAGE HYSTELESIS		$V_{BAT}$	$V_{BAT}$	$V_{BAT}$			
DUTY <sub>MAX</sub>	Max Duty Cycle			99		%		

## I<sup>2</sup>C INTERFACE TIMING REQUIREMENTS

Electrical Characteristics, T<sub>1</sub> = -40C to 125C, VIN = 5.3V (unless otherwise noted)

Symbol	Parameter	Standa	Standard Mode		Fast Mode	
-		Min	Max	Min	Max	
$f_{scl}$	I <sup>2</sup> C clock frequency	0	100	0	400	kHz
$t_{sch}$	I <sup>2</sup> C clock high time	4		0.6		μs
$t_{scl}$	I <sup>2</sup> C clock low time	4.7		1.3		μs
$t_{sp}$	I <sup>2</sup> C tolerable spike time	0	50	0	50	ns
t <sub>sds</sub>	I <sup>2</sup> C serial data setup time	250		100		ns
t <sub>sdh</sub>	I <sup>2</sup> C serial data hold time	0		0		μs
t <sub>icr</sub>	I <sup>2</sup> C input rise time		1000		300	ns
t <sub>icf</sub>	I <sup>2</sup> C input fall time		300		300	ns
t <sub>ocf</sub>	I <sup>2</sup> C output fall time; 10 pF to 400 pF bus		300		300	ns
t <sub>buf</sub>	I <sup>2</sup> C bus free time between Stop and Start	bus free time between Stop and Start 4.7 1.3			μs	
t <sub>sts</sub>	I <sup>2</sup> C Start or repeated Start condition setup time	Start or repeated Start condition setup time 4.7 0.6			μs	
$t_{\rm sth}$	I <sup>2</sup> C Start or repeated Start condition hold time	e 4 0.6			μs	
t <sub>sps</sub>	I <sup>2</sup> C Stop condition setup time	4		0.6		μs



### **FUNCTIONAL DESCRIPTION**

The TS52002 is a fully-integrated MPP regulator IC based on a highly-efficient switching topology. It includes a Maximum Power Point Tracking (MPPT) function to optimize its input voltage to extract the maximum possible power from a photovoltaic cell. A 1 MHz internal switching frequency facilitates low-cost LC filter combinations.

When the output voltage is below the termination voltage, the device will regulate to the maximum power point. This will continue as long as the output current is below the current limit and no fault has occurred. In order for the Maximum Power Point (MPP) regulation to be most effective, the output load needs to not allow high frequency transients in output voltage. This will cause the device to operate at a non optimal MPP point until the output voltage has remained static for several milliseconds.

As detailed in the Application Diagram, the external  $\mu$ C pulses the charging current based on a NiMH charging profile. The battery voltage and/or temperature is monitored to safely charge and ensure the battery is fully charged. One or two NiMH cells can be configured in series or parallel with a parallel configuration requiring two switches to allow the  $\mu$ C to manage the charging profile.

### **INTERNAL PROTECTION DETAILS**

#### **Internal Current Limit**

The current through the inductor is sensed on a cycle by cycle basis and if current limit is reached, it will abbreviate the cycle. Current limit is always active when the regulator is enabled.

#### **Thermal Shutdown**

If the temperature of the die exceeds 170C (typical), the SW outputs will tri-state to protect the device from damage. The nFLT and all other protection circuitry will stay active to inform the system of the failure mode. Once the device cools to 160C (typical), the device will attempt to start up again. If the device reaches 170C, the shutdown/restart sequence will repeat.

#### VIN Under-Voltage Lockout

The device is held in the off state until VIN reaches 3.15V. There is a 200mV hysteresis on this input, which requires the input to fall below 2.95V before the device will disable.

#### **VBAT Over-Voltage Protection**

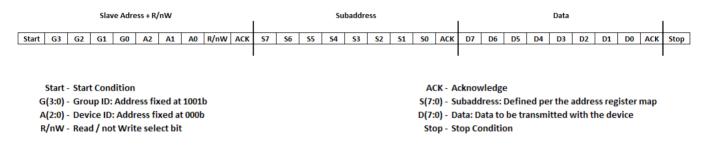
The TS52002 has an output protection circuit designed to shutdown the charging profile if the output voltage is greater than the termination voltage. Shutting down the charging profile puts the TS52002 in a fault condition.



### SERIAL INTERFACE

The TS52002 features an I<sup>2</sup>C slave interface which offers advanced control and diagnostic features. I<sup>2</sup>C operation offers fault and warning indicators. Whenever a fault is detected, the associated status bit in the STATUS register is set and the nFLT pin is pulled low. Whenever a warning is detected, the associated status bit in the STATUS register is set, but the nFLT pin is not pulled low. Reading of the STATUS register resets the fault and warning status bits, and the nFLT pin is released after all fault status bits have been reset.

# I<sup>2</sup>C SUBADDRESS DEFINITION



#### Figure 3: Sub-address in I<sup>2</sup>C Transmission

# I<sup>2</sup>C BUS OPERATION

The TS52002 has a slave I<sup>2</sup>C interface that supports standard and fast mode data rates, auto-sequencing, and is compliant to I<sup>2</sup>C standard version 3.0.

I<sup>2</sup>C is a two-wire serial interface where the two lines are serial clock (SCL) and serial data (SDA). SDA must be connected to a positive supply through an external pull-up resistor. The devices communicating on this bus can drive the SDA line low or release it to high impedance. The device that initiates the I<sup>2</sup>C transaction becomes the master of the bus. Communication is initiated by the master sending a Start condition, a high-to-low transition on SDA, while the SCL line is high. After the Start condition, the device address byte is sent, most significant bit (MSB) first, including the data direction bit (R/nW). After receiving the valid address byte, the device responds with an acknowledge (ACK). An ACK is a low on SDA during the high of the ACK related clock pulse. On the I<sup>2</sup>C bus, during each clock pulse only one data bit is transferred. The data on the SDA line must remain stable during the high pulse of the clock period, as changes in the data line at this time are interpreted as Start or Stop control commands. A low-to-high transition on SDA while the SCL input is high, indicates a Stop condition and is sent by the master (see Figure 4).

Any number of data bytes can be transferred from the transmitter to receiver between the Start and the Stop conditions. Each byte of eight bits is followed by one ACK bit. The SDA line must be released by the transmitter before the receiver can send an ACK bit. The receiver that acknowledges must pull down the SDA line during the ACK clock pulse, so that the SDA line is stable low during the high pulse of the ACK-related clock period. When a slave receiver is addressed, it must generate an ACK after each byte is received. Similarly, the master must generate an ACK after each byte that it receives from the slave transmitter. To ensure proper operation, setup and hold times must be met. An end of data is signaled by the master receiver to the slave transmitter by not generating an acknowledge after the last byte has been clocked out of the slave. This is done by the master receiver by holding the SDA line high. The transmitter must then release the data line to enable the master to generate a Stop condition.



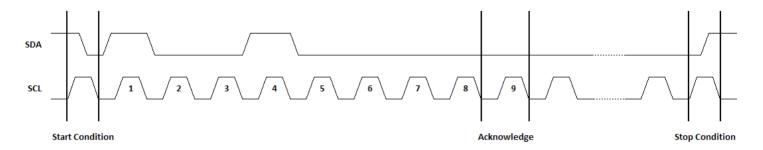


Figure 4: I<sup>2</sup>C Start / Stop Protocol

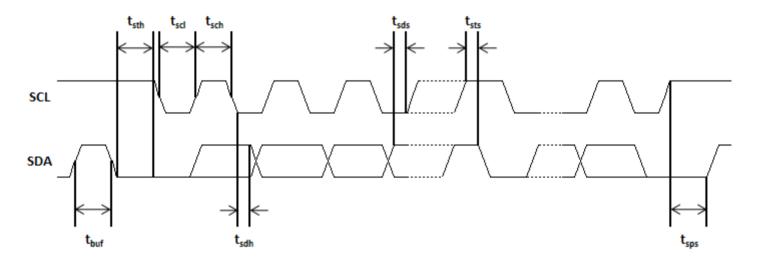


Figure 5: I<sup>2</sup>C Data Transmission Timing



# **REGISTER DESCRIPTION (Device Address = 0x48)**

REGISTER	ADDRESS (HEX)	NAME	DEFAULT	DESCRIPTION
0	00	STATUS	0x00	Status bit register
1-3	N/A	N/A	N/A	Register not implemented
4	04	CONFIG3 <sup>(1)</sup>	EEPROM	Configuration register
1-16	N/A	N/A	N/A	Registers not implemented
17	11	CONFIG_ENABLE	0x00	Enable configuration register access
18	12	EEPROM_CTRL <sup>(1)</sup>	0x00	EEprom control register

(1) CONFIG and EEPROM\_CTRL registers are only accessible when CONFIG\_ENABLE register is written.

## **STATUS REGISTER (STATUS)**

#### Address – 0x00h

DATA BIT	D7	D6	D5	D4	D3	D2	D1	D0
FIELD NAME	VBAT_OV	Not Used	Not Used	Not Used	TSD	Not Used	VIN_UV	Not Used
<b>READ/WRITE</b>	R	R	R	R	R	R	R	R

FIELD NAME	BIT DEFINITION <sup>(1)</sup>
VBAT_OV	VBAT over-voltage
TSD	Thermal shutdown
VIN_UV	VIN under-voltage

(1) Faults are defined as VBAT\_OV. Warnings are defined as TSD, and VIN\_UV. Faults cause the nFLT pin to be pulled low, Warnings do not cause the nFLT pin to be pulled low. All status bits are cleared after register read access. nFLT pin will go high impedance (open drain output) after the status register has been read and all status bits have been reset.



### **CONFIGURATION REGISTER (CONFIG3)**

Address – 0x04h

DATA BIT	D7	D6	D5	D4	D3	D2	D1	D0	
FIELD NAME	MAX_CHRG_CURR [3:0]				LD NAME MAX_CHRG_CURR [3:0] Not Used				
<b>READ/WRITE</b>	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	

FIELD NAME	BIT DEFINITION
MAX_CHRG_CURR[3:0]	Maximum charge current configuration
	0000 – 50 mA
	0001 – 100 mA
	0010 – 200 mA
	0011 – 300 mA
	0100 – 400 mA
	0101 – 500 mA
	0110 – 600 mA
	0111 – 700 mA
	1000 – 800 mA
	1001 – 900 mA
	1010 – 1000 mA
	1011 – 1100 mA
	1100 – 1200 mA
	1101 – 1300 mA
	1110 – 1400 mA
	1111 – 1500 mA

## ENABLE CONFIGURATION REGISTER (CONFIG\_ENABLE)

Address – 0x11h

DATA BIT	D7	D6	D5	D4	D3	D2	D1	D0
FIELD NAME	Not used	EN_CFG						
<b>READ/WRITE</b>	R	R	R	R	R	R	R	R/W
<b>RESET VALUE</b>	0	0	0	0	0	0	0	0

FIELD NAME	BIT DEFINITION
EN_CFG	Enable access control bit for configuration registers 2 and 4
	0 – Disable access
	1 – Enable access

# **EEPROM CONTROL REGISTER (EEPROM\_CTRL)**

Address – 0x12h

DATA BIT	D7	D6	D5	D4	D3	D2	D1	D0
FIELD NAME	Not used	EE_PROG						
<b>READ/WRITE</b>	R	R	R	R	R	R	R	R/W
<b>RESET VALUE</b>	0	0	0	0	0	0	0	0

FIELD NAME	BIT DEFINITION
EE_PROG <sup>(1)</sup>	EEPROM program control bit for configuration registers 2 and 4
	0 – Disable EEPROM programming
	1 – Enable EEPROM programming with data from configuration registers 2 and 4

(1) EE\_PROG Note: Inputs VIN and EN must be present for 200ms.

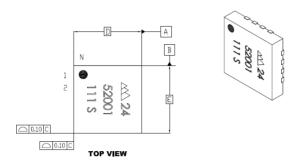


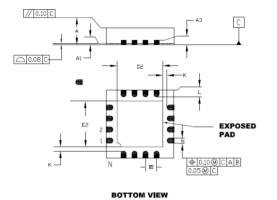
#### **EXTERNAL COMPONENT SELECTION**

The internal compensation is optimized for a 4.7uF output capacitor and a 4.7uH inductor. To keep the output ripple low, a low ESR (less than 35mOhm) ceramic is recommended.



### PACKAGE MECHANICAL DRAWINGS





Pitch 0.65 BSC е Overall Height 0.80 0.90 1.00 А Standoff Α1 0.00 0.02 0.05 Contact Thickness Α3 0.20 REF Overall Length 4.00 BSC D Exposed Pad Width E2 2.55 2.80 2.70 Overall Width Е 4.00 BSC Exposed Pad Length D2 2.70 2.80 2.55 Contact Width b 0.25 0.30 0.35 Contact Length 0.30 0.40 0.50 L Contact-to-Exposed Pad 0.20 к

Units

Ν

MIN

Dimensions Limits

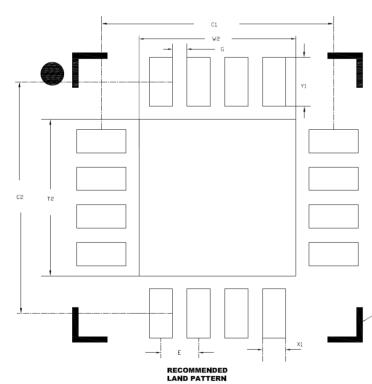
Number of Pins

MILLIMETERS

NOM

16

MAX



	Units	Ν	<b>MILLIMETER</b>	S
Dimer	MIN	NOM	MAX	
Contact Pitch	E		0.65 BSC	
Optional Center Pad Width	W2	-	-	2.70
Optional Center Pad Length	T2	-	-	2.70
Contact Pad Spacing	C1	-	4.00	-
Contact Pad Spacing	C2	-	4.00	-
Contact Pad Width (X16)	X1	-	-	0.40
Contact Pad Length (X16)	Y1	-	-	0.85
Distance Between Pads	G	0.25	-	-

Notes: Dimensions and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances REF: Refernce Dimension, usually without tolerance, for information only.

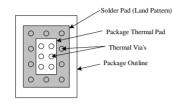
Silk Screem



# APPLICATION USING A MULTI-LAYER PCB

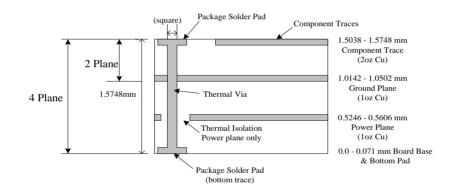
To maximize the efficiency of this package for application on a single layer or multi-layer PCB, certain guidelines must be followed when laying out this part on the PCB.

#### The following are guidelines for mounting the exposed pad IC on a Multi-Layer PCB with ground a plane.



Package and PCB Land Configuration For a Multi-Layer PCB

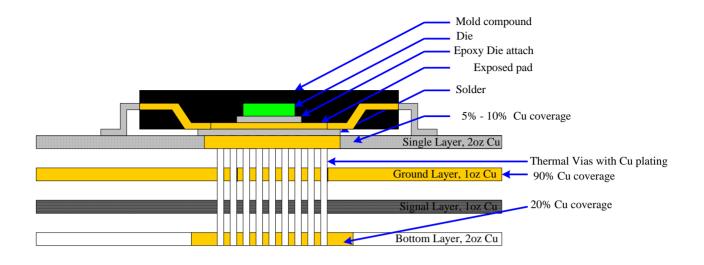
#### JEDEC standard FR4 PCB Cross-section:



Multi-Layer Board (Cross-sectional View)

In a multi-layer board application, the thermal vias are the primary method of heat transfer from the package thermal pad to the internal ground plane. The efficiency of this method depends on several factors, including die area, number of thermal vias, thickness of copper, etc.

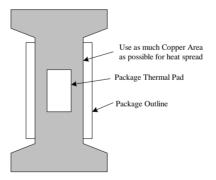




Note: NOT to Scale

The above drawing is a representation of how the heat can be conducted away from the die using an exposed pad package. Each application will have different requirements and limitations and therefore the user should use sufficient copper to dissipate the power in the system. The output current rating for the linear regulators may have to be de-rated for ambient temperatures above 85C. The de-rate value will depend on calculated worst case power dissipation and the thermal management implementation in the application.

#### APPLICATION USING A SINGLE LAYER PCB



Layout recommendations for a Single Layer PCB: utilize as much Copper Area for Power Management. In a single layer board application the thermal pad is attached to a heat spreader (copper areas) by using low thermal impedance attachment method (solder paste or thermal conductive epoxy).

In both of the methods mentioned above it is advisable to use as much copper traces as possible to dissipate the heat.

#### **IMPORTANT:**

If the attachment method is NOT implemented correctly, the functionality of the product is not guaranteed. Power dissipation capability will be adversely affected if the device is incorrectly mounted onto the circuit board.



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